

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring high thermal cycling performance and high junction temperature capability ($T_{i(max)} = 150$ °C).

2. Features and benefits

- · High junction operating temperature capability
- High thermal cycling performance
- High voltage capability
- Planar passivated for voltage ruggedness and reliability •

3. Applications

- Ignition circuits
- Motor control •
- Protection circuits e.g. SMPS inrush current
- Voltage regulation

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	600	V
V _{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	180	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$	-	-	198	A
Tj	junction temperature		-	-	150	°C
I _{T(AV)}	average on-state current	half sine wave; $T_h \le 81 \text{ °C}$; Fig. 1	-	-	10.2	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _h ≤ 81 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	16	A
Static chara	acteristics				·	
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _i = 25 °C; <u>Fig. 7</u>	3.5	5	6	mA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs

5. Pinning information

Table 2	. Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	A H K
2	А	anode		Ğ sym037
3	G	gate		Symoor
mb	n.c.	mounting base; isolated		
			TO-220F (SOT186A)	

6. Ordering information

Table 3. Ordering information

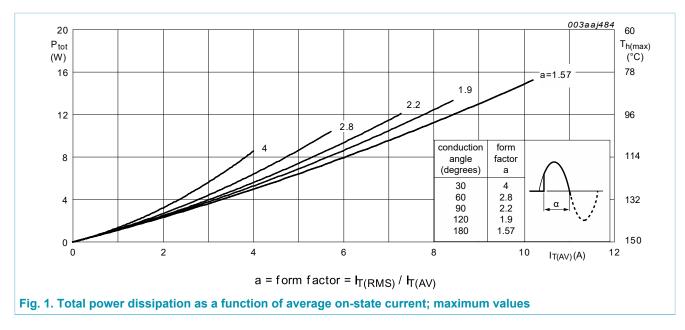
Type number	Package					
	Name	Description	Version			
TYN16X-600CTN (9340 690 08127)	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A			

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

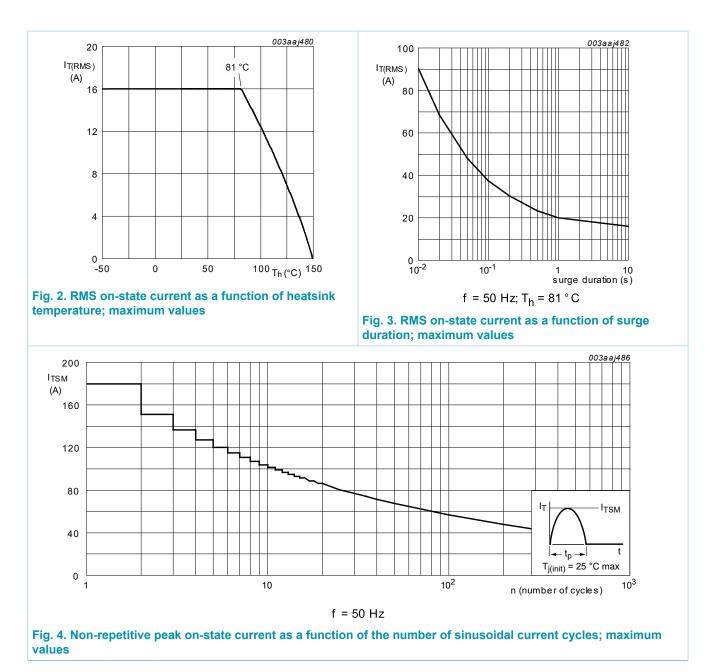
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
V _{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; T _h ≤ 81 °C; <u>Fig. 1</u>	-	10.2	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _h ≤ 81 °C; <u>Fig. 2; Fig. 3</u>	-	16	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	180	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	198	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	162	A²s
dl _T /dt	rate of rise of on-state current	I_T = 40 A; I_G = 200 mA; dI_G/dt = 200 mA/ μ s	-	50	A/µs
I _{GM}	peak gate current		-	4	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	10	W
P _{G(AV)}	average gate power	over any 20 ms period	-	1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C



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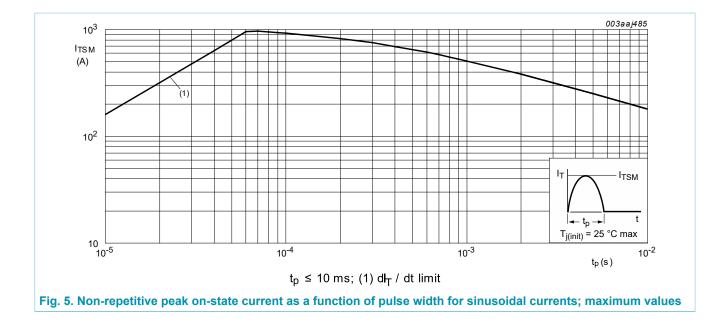
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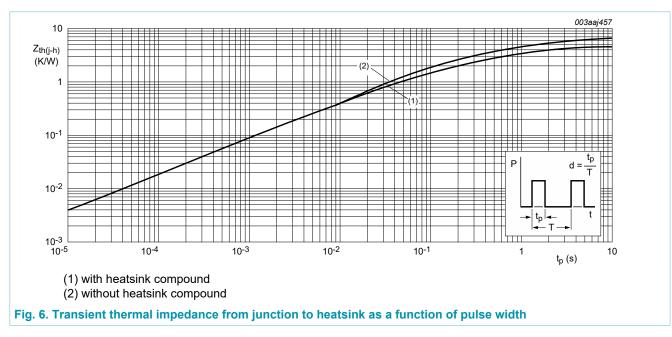


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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	with heatsink compound; Fig. 6	-	-	4.5	K/W
		without heatsink compound; Fig. 6	-	-	6.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



9. Isolation characteristics

Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from anode to external heatsink; f = 1 MHz; T _h = 25 °C	-	10	-	pF

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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		l.			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	3.5	5	6	mA
IL .	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	-	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	I _T = 32 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.6	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.7	1.3	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C; Fig. 11	0.2	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 150 °C	-	0.2	1	mA
I _R	reverse current	V _R = 600 V; T _j = 150 °C	-	0.2	1	mA
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 40 A; V _D = 600 V; I _G = 100 mA; dI _G /dt = 5 A/µs; T _j = 25 °C	-	2	-	μs
tq	commutated turn-off time		-	70	-	μs

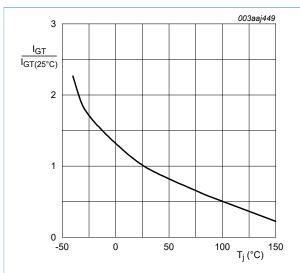


Fig. 7. Normalized gate trigger current as a function of junction temperature

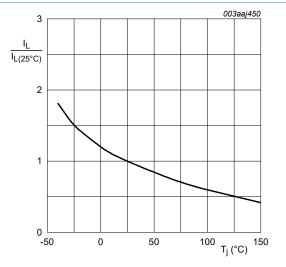
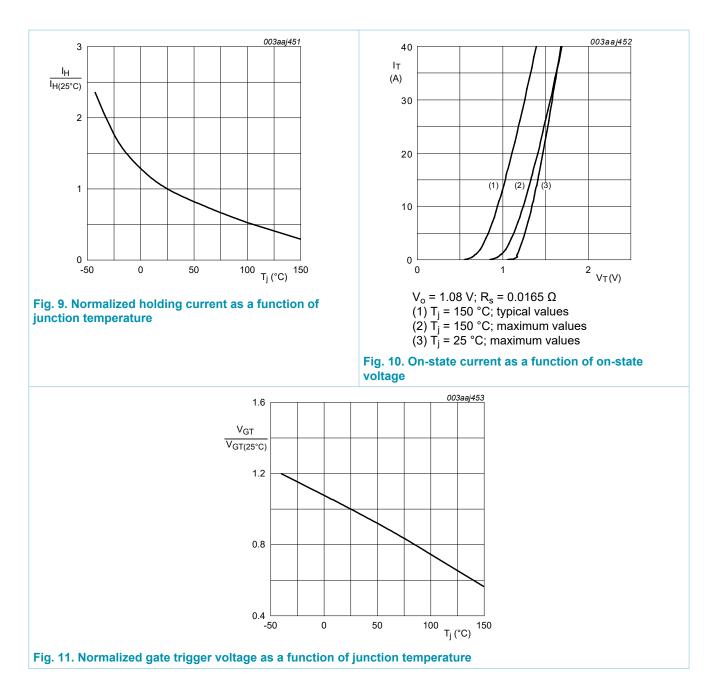


Fig. 8. Normalized latching current as a function of junction temperature

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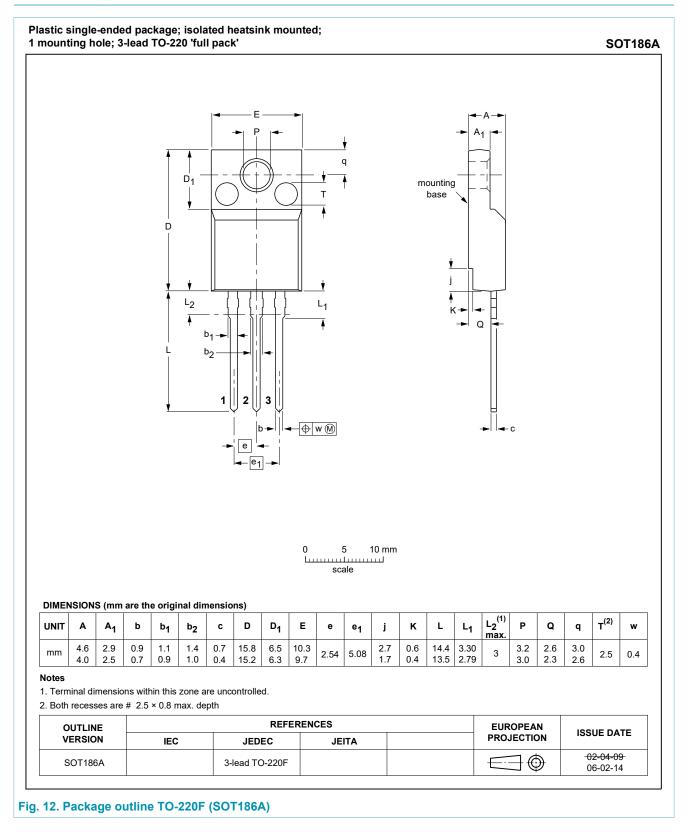
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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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